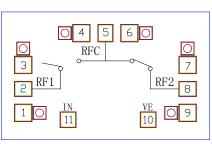


Features

- ·Freq: DC-40.0 GHz
- ·Insertion Loss: 1.7 dB
- ·Isolation: 35 dB
- ·Input Return Loss: -16 dB
- ·On-state output return loss: -16 dB
- ·50Ω Input/ Output
- ·Die Size: 1.3×0.8×0.1mm³

Functional Diagram



General Description

The MC15002 is a reflective SPDT switch which operates during DC-40.0 GHz. The typical insertion loss is 1.7dB and the isolation is 35dB. With 0V/+3.3V logic control, an external -5V power bias is required, the typical bias current is 2mA, and the switching speed is less than 50ns.

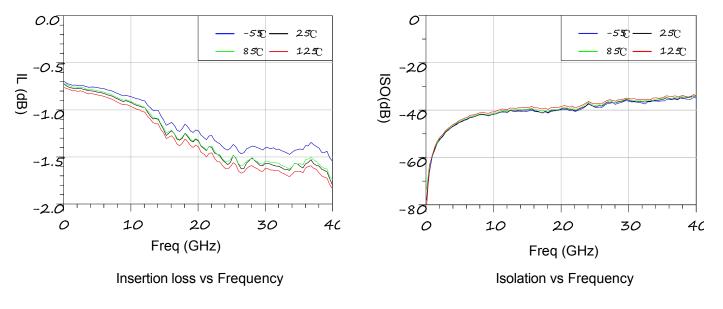
The Chip applies the on-chip metallization through-hole technology thus no need for additional grounding measures which makes it easy and convenient to use. The backside of the chip is metallized. suitable for adhesive conductive bonding or eutectic mounting process.

Electrical Specifications (TA=+25°C, 50Ω system,0V/+3.3V Control (0/+5V Control Compatible))

Parameter		Min.	Тур.	Max.	Unit
Frequency Range	Freq	DC	-	40.0	GHz
Insertion Loss	IL	-	1.7	-	dB
Isolation	ISO	-	35	-	dB
Input Return Loss	IRL	-	-16	-	dB
On-state output return loss	ORL	-	-16	-	dB
Switching time	Т	-	-	50	ns
Bias current	I	-	2	-	mA

[1] The chips are 100% DC and RF tested.

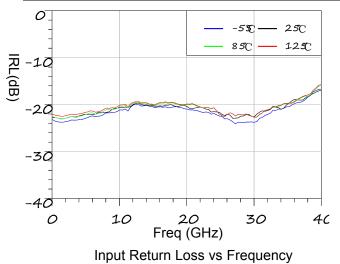
Typical Testing Characteristics

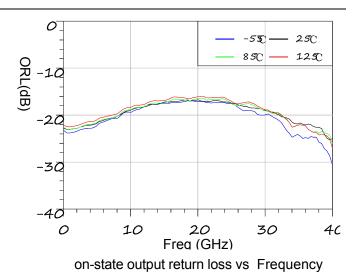


MC15002



GaAs MMIC Reflective SPDT Switch, DC-40.0 GHz







GaAs MMIC Reflective SPDT Switch, DC-40.0 GHz

Absolute Maximum Ratings

Parameter Limits	Value			
Input Power,50Ω	23dBm			
Control Voltage	0V~+5V			
Storage Temperature	-65~+150℃			
Operating Temperature	-55~+125℃			
Mounting Temperature (30s, N ₂ Protection)	300 °C			
Eveneding the above conditions may cause permanent				

Exceeding the above conditions may cause permanent damage to the chip



Pad Descriptions

This product is ESD(Electrostatic discharge) sensitive. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

Assembling in a clean environment.

- Avoiding rapid temperature changes during the mounting process.
- Do not touch the surface or use dry/wet chemical methods to clean the surface
- ·2 bonding wires for input and output (in figure 八), the bonding wires should be as short as possible. ·Storing in a dry, N₂ protection environment.

650 800 5 4 60 Ο RFC RF2 RF1 320 320 11 10 0 1300 420 920 0

Notes:

1. Unit:µm

Outline Drawing

- 2. Back Side Metallization: Gold
- 3. Back side metal is ground
- 4. Bonding pad size: 100 µm
- 5. Outline Dimensional Tolerance:±50 µm

Pad No.	Function	Description	Interface Schematic
5	RFC	RF signal input, 50 Ω matched, without blocking capacitor inside	_⊢ ↓⊙RFIN
2, 8	RFOUT	RF Signal output, 50 Ω matched, without blocking capacitor inside	-⊧∘RFOUT
11	IN	DC control signal, 0V/+3.3V voltage matched	
10	VE	-5V Bias voltage	°VE ⊣⊤_
1, 3, 4, 6, 7, 9	GND	Grounding pad for probe test	o GND ⊥_
Die Bottom	GND	Die bottom must be connected to RF/DC ground	o GND ⊥

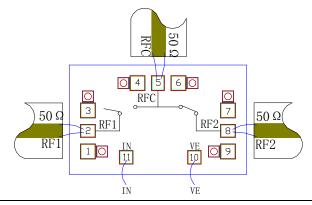
Control Voltage Range

Тур.	Control Voltage Range		
0V	0V~+0.5V		
+3.3V	+3V~+5V		

Control Logic

Power Voltage	Control Input	On-off state	
VE	IN	RF1	RF2
-5V	0V	ON	OFF
-5V	+3.3V	OFF	ON

Assembly Diagram



MC15002